



Docket No.: 1630-0135P
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Johngeon SHIN

Application No.: 10/765,100

Confirmation No.: 9721

Filed: January 28, 2004

Art Unit: 2818

For: CRYSTAL GROWTH METHOD OF
NITRIDE SEMICONDUCTOR

Examiner: M. H. C. Tran

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated May 26, 2005, please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 6 of this paper.

Remarks/Arguments begin on page 17 of this paper.